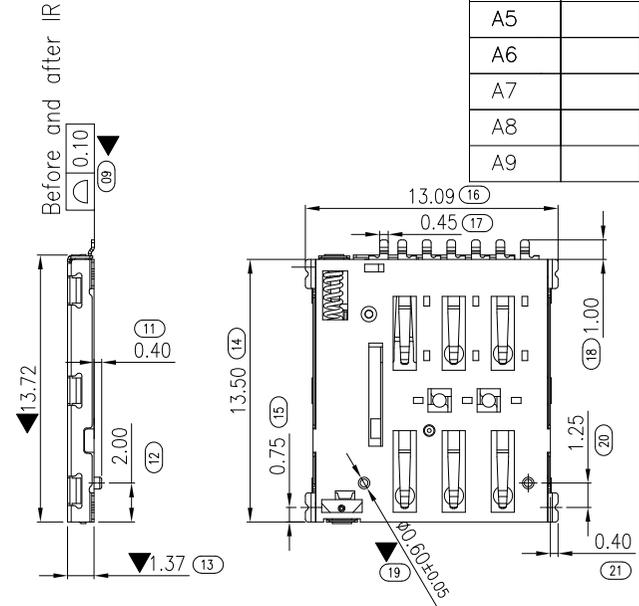
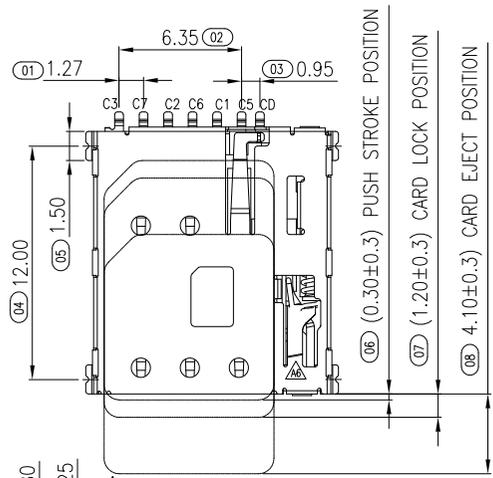
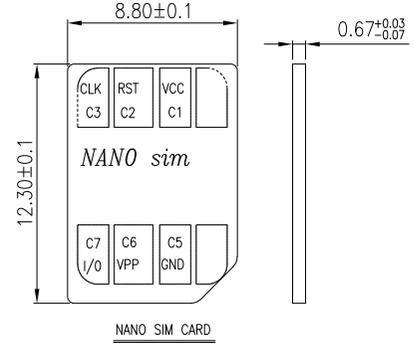
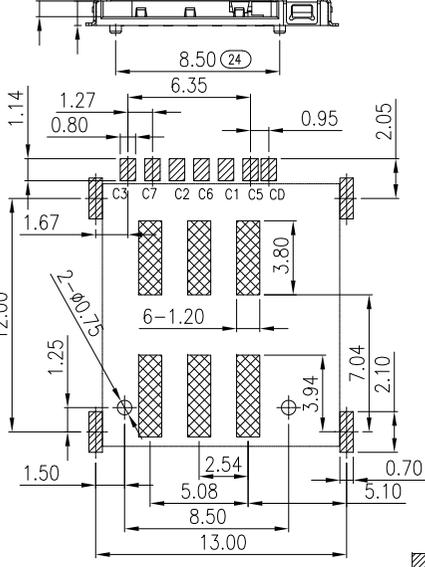


GP Component

REV.	ECN NO.	LOCATIONS	DESCRIPTION	DATE	DESIGN
A0			Initial	2016/10/27	Phebe Su
A1.A2			Update.Change housing	2016/10/28.2016/12/22	Phebe Su
A3.A4			Modify.Change	2017/06/06.2017/07/07	Phebe Su
A5			Add the focus size mark	2017/12/01	Phebe Su
A6			Change angle of Slider	2017/12/07	Summer Wang
A7			Change 8.90 to 9.0±0.08	2018/01/10	Phebe Su
A8			Add notes	2018/11/30	Summer Wang
A9			Correct bottom view	2019/05/17	Phebe Su



Applicable to 3 times IR before and after specification.



Specification:

MATERIAL:

Insulator: High Temperature Thermoplastic, UL 94V-0. Black
 Contact: Copper Alloy
 SHELL: STANLESS STEEL

PLATING:

Contact Area: Gold flash.
 Solder Area: Gold flash plated. Under plate: nickel.
 Shell: Nickel plated over all.
 Solder Area: Gold flash.

Electrical:

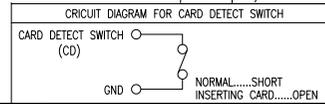
Current Rating :1.0A max.
 Voltage Rating :30V
 Ambient Temperature Range :-40° C~+85° C
 Storage Temperature Range :-40° C~+85° C
 Humidity: 80% R.H. Max.
 Contact Resistance:50mΩmax.
 Insulation Resistance:1000MΩ MIN 500V DC
 Mating Cycles:5,000 Insertions
 Solder ability:260+0/-5° C. 30±10s.

Performance:

Mating force: 5.7 N
 Unmating force: 2.1 N
 Pop-up force: 6.32 N
 Add the focus size mark ▼

MATRIX PART NO:
MSM - 01 - 01 - 06 - 13 - 23
 Matrix NANO SIM
 01: Push
 02: Non-Push
 Plating 01: G/F 30: 30u
 Series Number
 Height
 Pin number 06: 6pin

RECOMMENDED PCB LAYOUT
 GENERAL TOLERANCE ±0.05



SIM pin assignment	PIN#	Name
C1	VCC	供电电压
C2	RST	重置
C3	CLK	时钟
C5	GND	接地
C6	VPP	程序电压
C7	I/O	输入输出



Matrix Electronics Co.,Ltd

TOLERANCE: X.X ±0.30 X.XX ±0.20 X.XXX ±0.10 ANGLE: ±3°		DESIGN BY : Phebe Su	DATE : 2019/05/17	PART NAME: NANO-SIM PUSH/PUSH 1.37H	
UNIT: mm [inch]		CHECKED BY: Vicky Hsieh	DATE : 2019/05/17	PART NO.	MSM-01-01-06-13-23
SCALE:1:1 SIZE:A4		APPROVED BY1: Richard Hsieh	DATE : 2019/05/17	MOLD NO.	NA
		APPROVED BY2: Richard Hsieh	DATE : 2019/05/17	DRAW NO.	
				SHEET NO.	1 OF 1